Not For New Designs

IXYS
INTEGRATED CIRCUITS DIVISION



LCB110
350V, 120mA Single-Pole, Normally Closed Relay

Parameter	Ratings	Units
Blocking Voltage	350	V_P
Load Current	120	mA_{rms} / mA_{DC}
On-Resistance (max)	35	Ω

Features
- 3750V_{rms} Input/Output Isolation
- Low Drive Power Requirements
- FCC Compatible
- VDE Compatible
- No EMI/RFI Generation
- Small 6-Pin Package
- Surface Mount Tape & Reel Version Available

Applications
- Telecommunications
  - Telecom Switching
  - Tip/Ring Circuits
  - Modem Switching (Laptop, Notebook, Pocket Size)
  - Hook Switch
  - Dial Pulsing
  - Ground Start
  - Ringing Injection
- Instrumentation
- Multiplexers
- Data Acquisition
- Electronic Switching
- I/O Subsystems
- Meters (Watt-Hour, Water, Gas)
- Medical Equipment-Patient/Equipment Isolation
- Security
- Industrial Controls

Description
The LCB110 is a single-pole, normally closed (1-Form-B) relay that uses optically coupled MOSFET technology to provide 3750V_{rms} of input to output isolation.

Its optically coupled outputs, which use the patented OptoMOS architecture, are controlled by a highly efficient infrared LED.

The LCB110 has low on-resistance and is well suited for most applications requiring a normally closed relay.

Approvals
- UL Recognized Component: File # E76270
- CSA Certified Component: Certificate # 1175739
- TUV EN 62368-1: Certificate # B 082667 0008

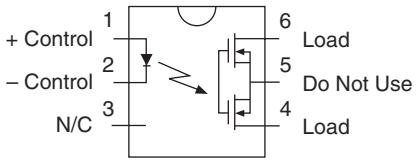
Ordering Information

Part #	Description
LCB110	6-Pin DIP (50/Tube)
LCB110S	6-Pin Surface Mount (50/Tube)
LCB110STR	6-Pin Surface Mount (1000/Reel)

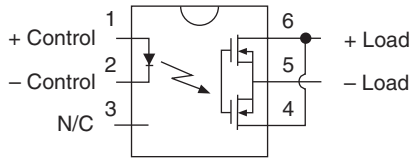
* For other packaging options consult factory.

Pin Configuration

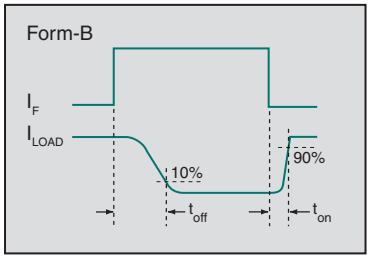
AC/DC Configuration



DC Only Configuration



Switching Characteristics of Normally Closed Devices



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Absolute Maximum Ratings @ 25ºC

Parameter	Ratings	Units
Blocking Voltage	350	V_P
Reverse Input Voltage	5	V
Input Control Current	50	mA
Peak (10ms)	1	A
Input Power Dissipation [1]	150	mW
Total Power Dissipation [2]	800	mW
Isolation voltage, Input to Output	3750	V_{rms}
Operational Temperature, Ambient	-40 to +85	°C
Storage Temperature	-40 to +125	°C

[1] Derate linearly 1.33 mW / ºC
[2] Derate output power linearly 6.67 mW / ºC

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Electrical Characteristics @ 25ºC

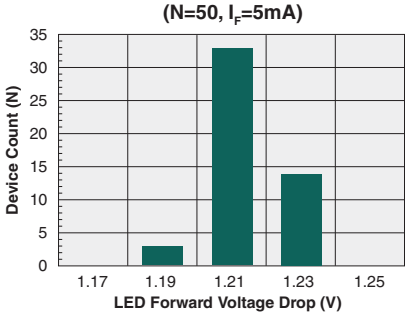
Parameter	Conditions	Symbol	Min	Typ	Max	Units
Output Characteristics						
Blocking Voltage	I_L=1µA	V_{DRM}	350	-	-	V_P
Load Current						
Continuous, AC/DC Configuration	-	I_L	-	-	120	mA_{rms} / mA_{DC}
Continuous, DC Configuration					200	mA_{DC}
Peak	t=10ms	I_L	-	-	±350	mA_P
On-Resistance [1]						
AC/DC Configuration	I_L=120mA	R_{ON}	-	23	35	Ω
DC Configuration	I_L=200mA		-	7	10	
Off-State Leakage Current	I_F=5mA, V_L=350V_P	I_{LEAK}	-	-	1	µA
Switching Speeds						
Turn-On	I_F=5mA, V_L=10V	t_{on}	-	0.38	3	ms
Turn-Off		t_{off}	-	0.93	3	
Output Capacitance	I_F=5mA, V_L=50V, f=1MHz	C_{OUT}	-	25	-	pF
Input Characteristics						
Input Control Current to Activate	I_L=120mA	I_F	-	-	5	mA
Input Control Current to Deactivate	-	I_F	0.4	0.7	-	mA
Input Voltage Drop	I_F=5mA	V_F	0.9	1.2	1.4	V
Reverse Input Current	V_R=5V	I_R	-	-	10	µA
Common Characteristics						
Input to Output Capacitance	-	$C_{I/O}$	-	3	-	pF

[1] Measurement taken within 1 second of on-time.

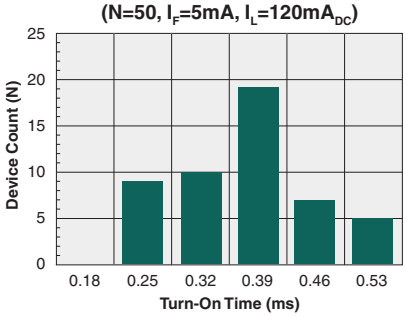
NEND

PERFORMANCE DATA*

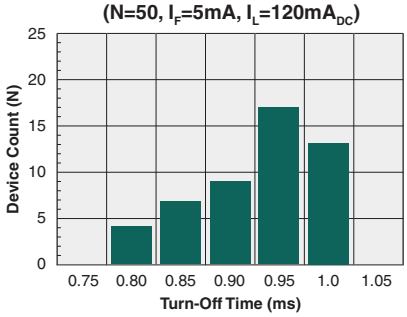
Typical LED Forward Voltage Drop
(N=50, I_F=5mA)



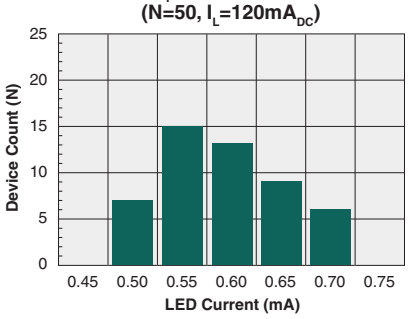
Typical Turn-On Time
(N=50, I_F=5mA, I_L=120mA$_{DC}$)



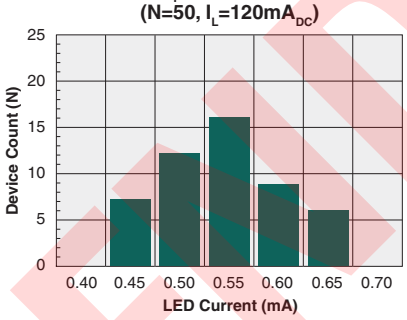
Typical Turn-Off Time
(N=50, I_F=5mA, I_L=120mA$_{DC}$)



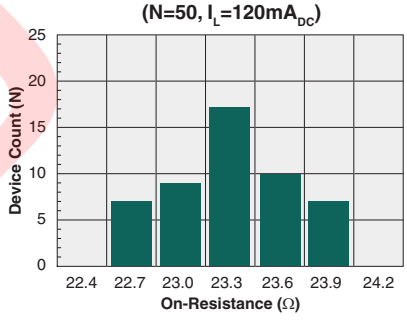
Typical I_F for Switch Operation
(N=50, I_L=120mA$_{DC}$)



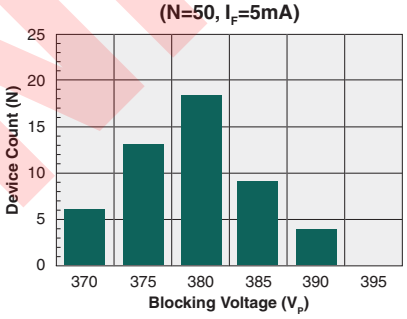
Typical I_F for Switch Dropout
(N=50, I_L=120mA$_{DC}$)



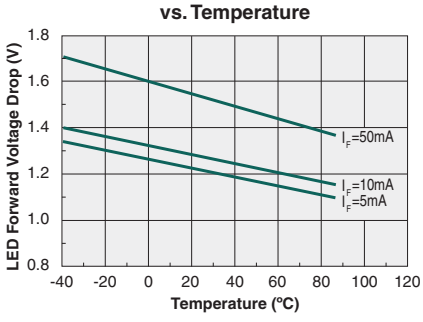
Typical On-Resistance Distribution
(N=50, I_L=120mA$_{DC}$)



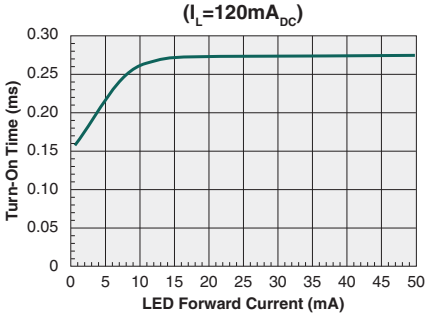
Typical Blocking Voltage Distribution
(N=50, I_F=5mA)



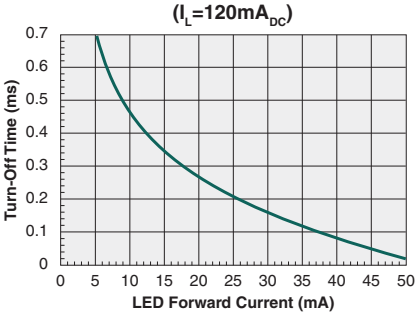
Typical LED Forward Voltage Drop
vs. Temperature



Typical Turn-On Time
vs. LED Forward Current
(I_L=120mA$_{DC}$)



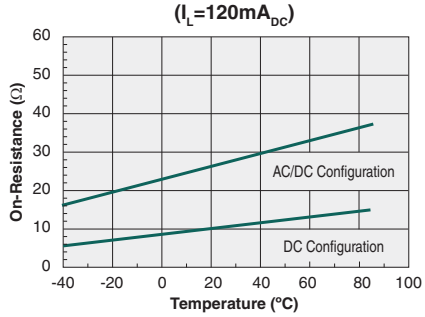
Typical Turn-Off Time
vs. LED Forward Current
(I_L=120mA$_{DC}$)



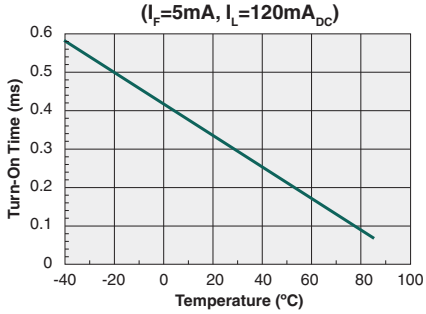
*Unless otherwise noted, data presented in these graphs is typical of device operation at 25ºC.

PERFORMANCE DATA*

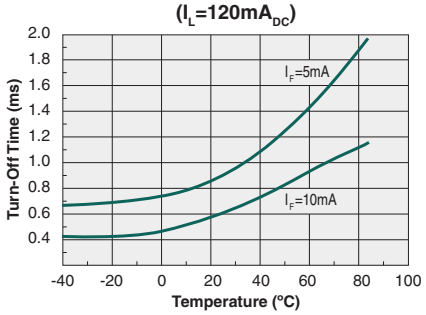
Typical On-Resistance vs. Temperature (I_L=120mA$_{DC}$)



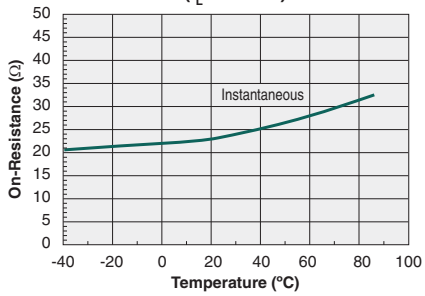
Typical Turn-On Time vs. Temperature (I_F=5mA, I_L=120mA$_{DC}$)



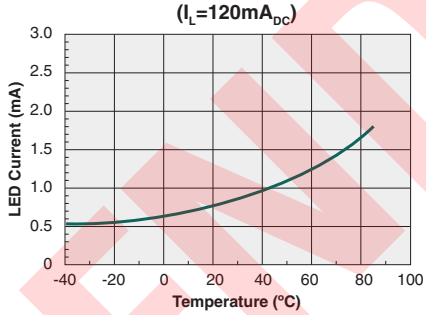
Typical Turn-Off Time vs. Temperature (I_L=120mA$_{DC}$)



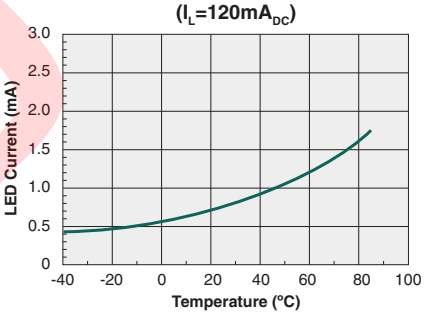
Typical On-Resistance vs. Temperature (I_L=100mA)



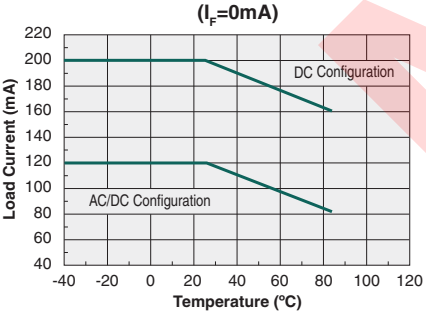
Typical I_F for Switch Operation vs. Temperature (I_L=120mA$_{DC}$)



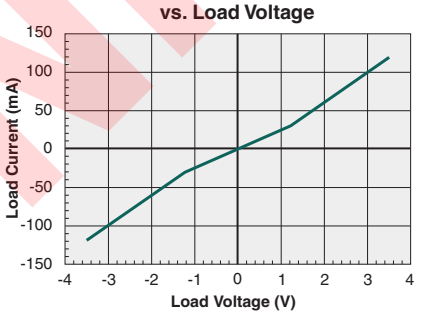
Typical I_F for Switch Dropout vs. Temperature (I_L=120mA$_{DC}$)



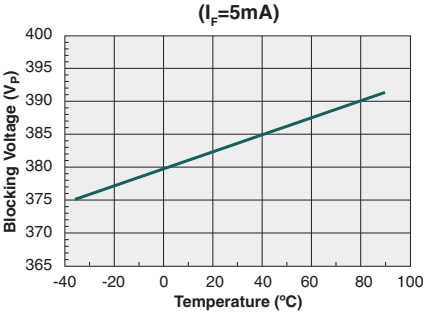
Maximum Load Current vs. Temperature (I_F=0mA)



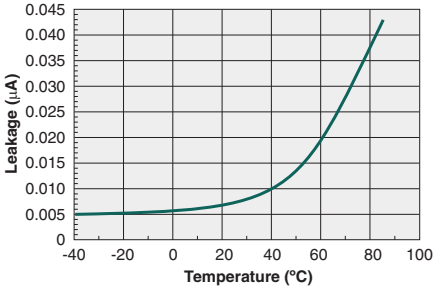
Typical Load Current vs. Load Voltage



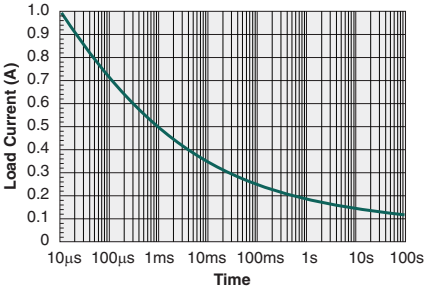
Typical Blocking Voltage vs. Temperature (I_F=5mA)



Typical Leakage vs. Temperature Measured Across Pins 4&6 (I_F=5mA, V_L=350V)



Energy Rating Curve



*Unless otherwise noted, data presented in these graphs is typical of device operation at 25°C.

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Manufacturing Information

Moisture Sensitivity

All plastic encapsulated semiconductor packages are susceptible to moisture ingression. IXYS Integrated Circuits classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Classification
LCB110S	MSL 1

ESD Sensitivity

This product is ESD Sensitive, and should be handled according to the industry standard **JESD-625**.

Soldering Profile

Provided in the table below is the **IPC/JEDEC J-STD-020** Classification Temperature (T_C) and the maximum total dwell time (t_P) in all reflow processes that the body temperature of these surface mount devices may be (T_C - 5)°C or greater. The device's body temperature must not exceed the Classification Temperature at any time during reflow soldering processes.

Device	Classification Temperature (T_c)	Dwell Time (t_P)	Max Reflow Cycles
LCB110S	250°C	30 seconds	3

For through-hole devices, the maximum pin temperature and maximum dwell time through all solder waves is provided in the table below. Dwell time is the interval beginning when the pins are initially immersed into the solder wave until they exit the solder wave. For multiple waves, the dwell time is from entering the first wave until exiting the last wave. During this time, pin temperatures must not exceed the maximum temperature given in the table below. Body temperature of the device must not exceed the limit shown in the table below at any time during the soldering process.

Device	Maximum Pin Temperature	Maximum Body Temperature	Maximum Dwell Time	Wave Cycles
LCB110	260°C	250°C	10 seconds*	1

*Total cumulative duration of all waves.

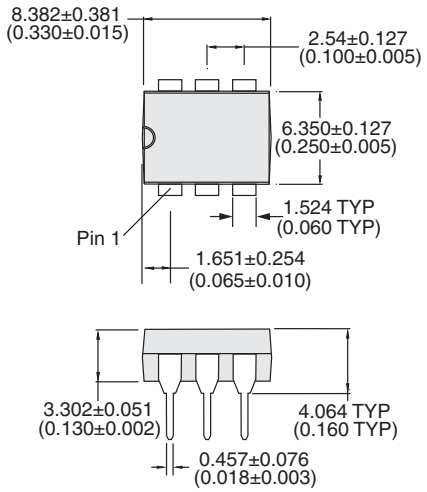
Board Wash

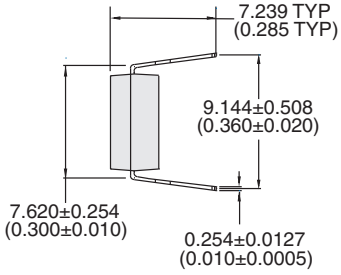
IXYS Integrated Circuits recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.

NEND

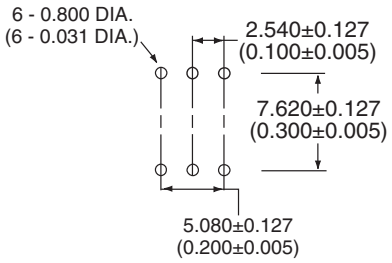
MECHANICAL DIMENSIONS

LCB110





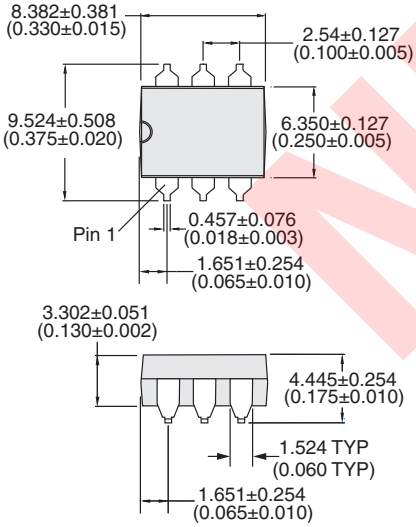
PCB Hole Pattern

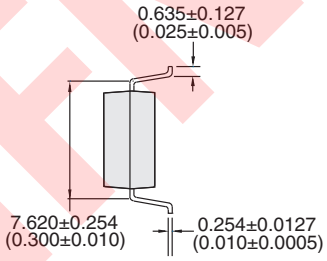


Controlling dimension: inches

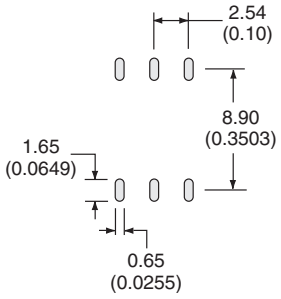
Dimensions
mm
(inches)

LCB110S





PCB Land Pattern



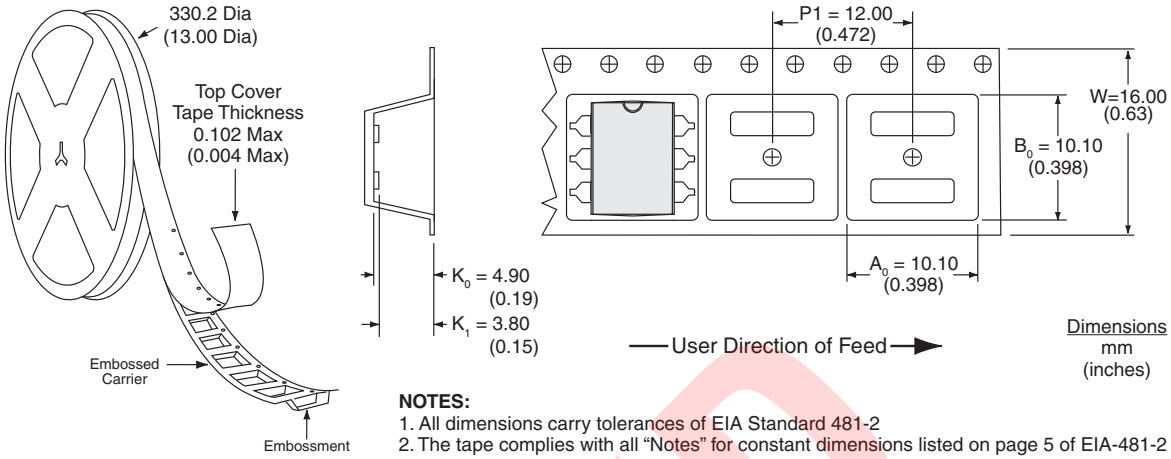
Controlling dimension: inches

Dimensions
mm
(inches)

NEND

Not For New Designs

LCB110STR Tape & Reel



NOTES:
1. All dimensions carry tolerances of EIA Standard 481-2
2. The tape complies with all "Notes" for constant dimensions listed on page 5 of EIA-481-2

NFND

For additional information please visit our website at: https://www.ixysic.com

IXYS
A Littelfuse Technology

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11/2/2021